



Optical investigation of excitons in GaN:Mn

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Aim of the research

- Determination of GaN:Mn energy gap variation with Mn concentration
- Quantitative observation of giant Zeeman splitting of A, B **and C** excitons in GaN:Mn

Compare to : Pacuski,

PRB'07

- Determination of both exchange constants $N_0\alpha$ and $N_0\beta$ of Mn^{3+} ion interaction with band carriers in GaN:Mn

Compare to GaAs: Szczytko, PRB'99; Krebs, PRB'09;

Samples



High res. transmission electron microscopy
& Synchrotron x-ray diffraction
& Extended x-ray absorption fine structure



No crystallographic phase separation

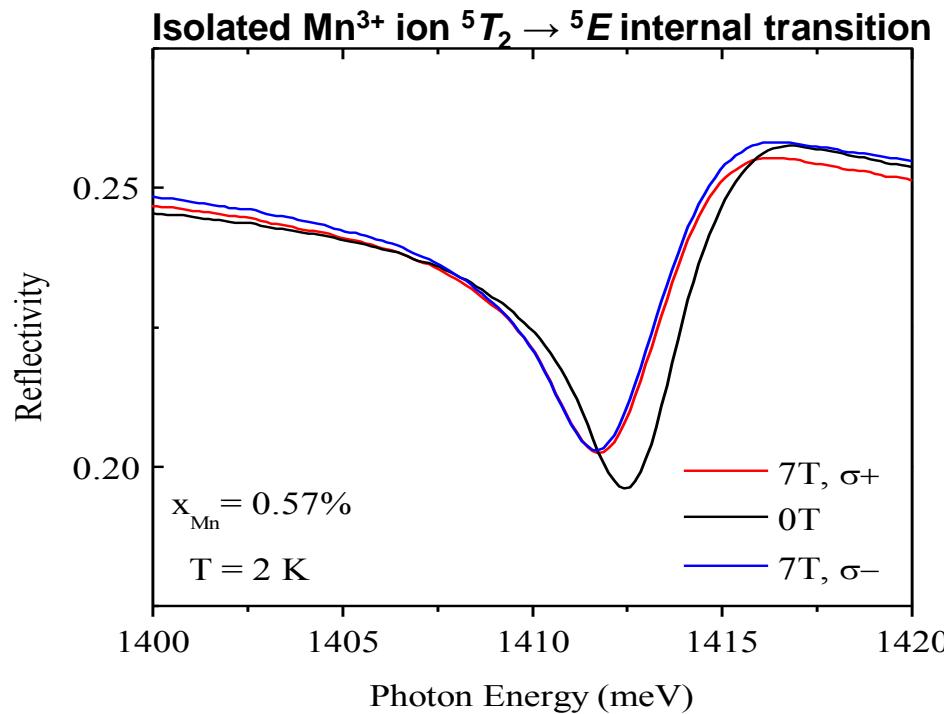


Mn ions occupy Ga-substitutional sites

Grown by MOVPE on GaN buffer

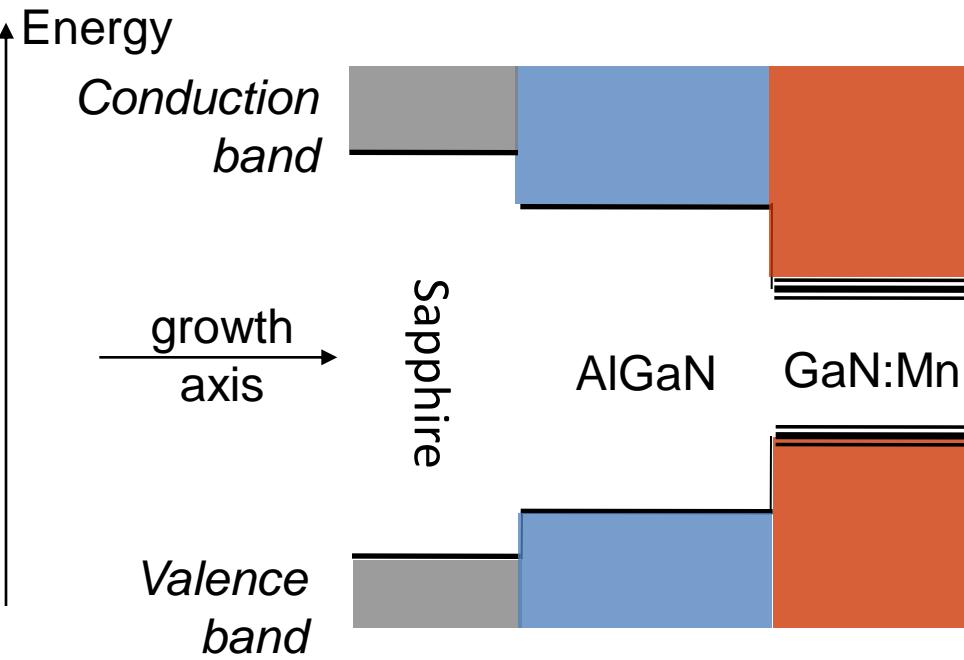
$x_{\text{Mn}} = 0.14 \text{ \% to } 0.8 \text{ \%}$ determined by SQUID and SIMS

Samples from the same series



→ Presence of isolated Mn³⁺ ions confirmed

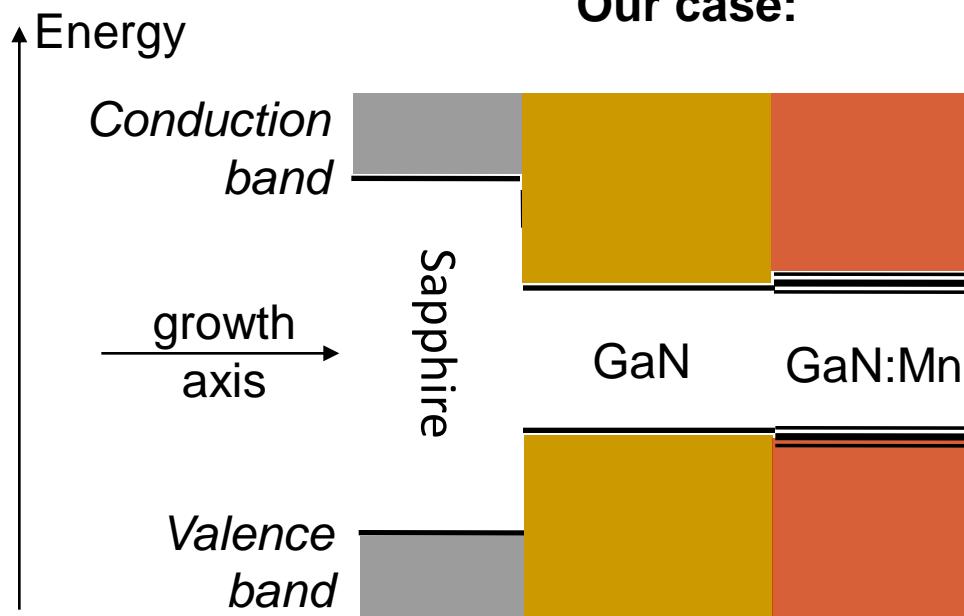
Compare to : Wołoś, PRB'04, Marcet, PRB'06



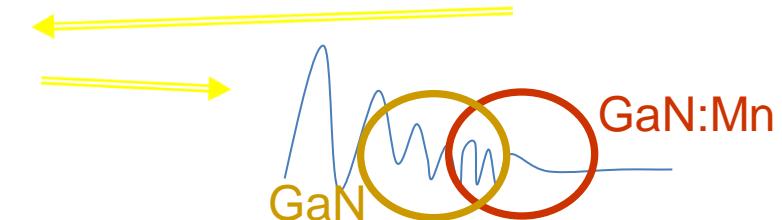
Samples



Excitons in GaN:Mn and AlGaN separated spectrally but structure strained

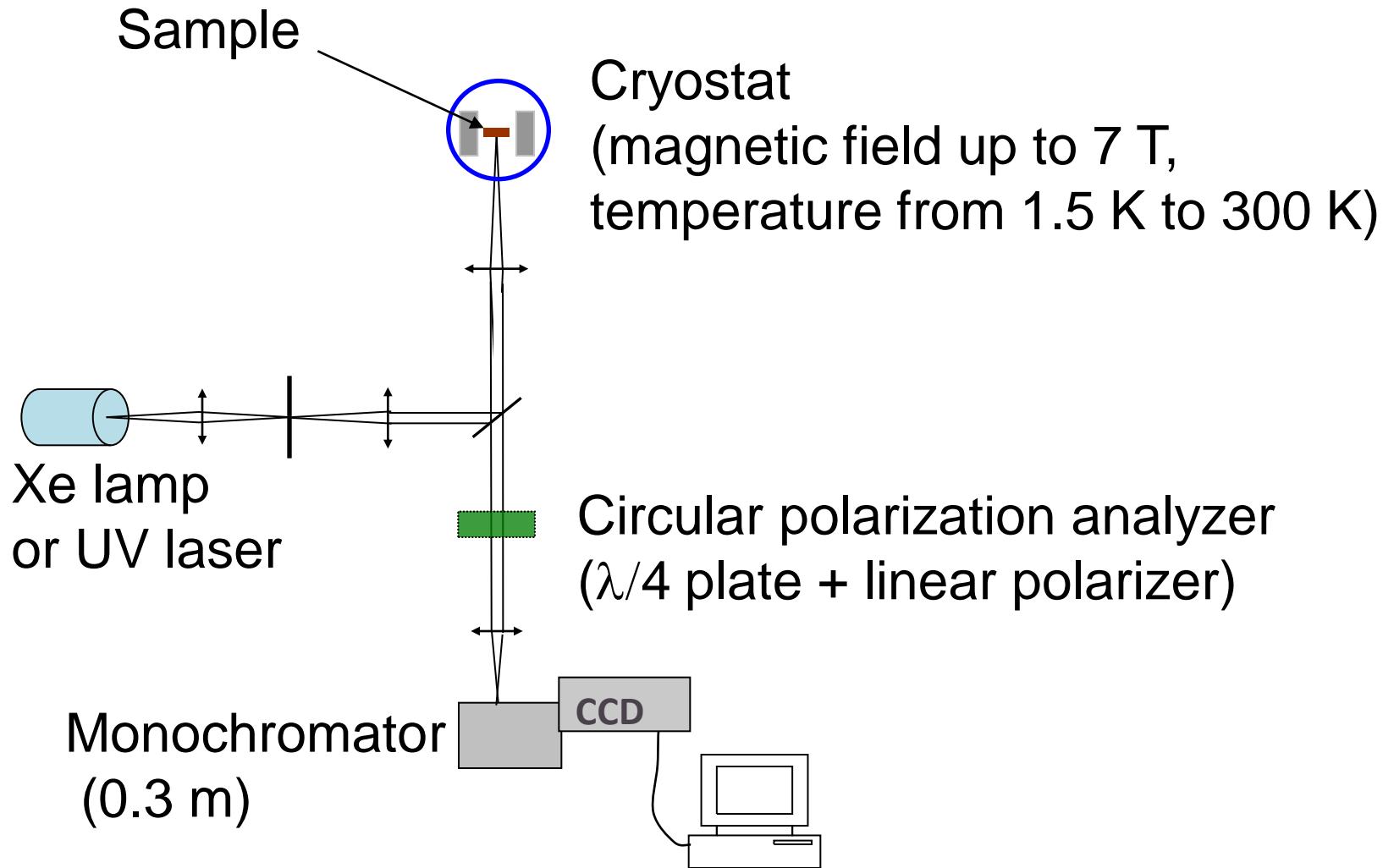


Our case:

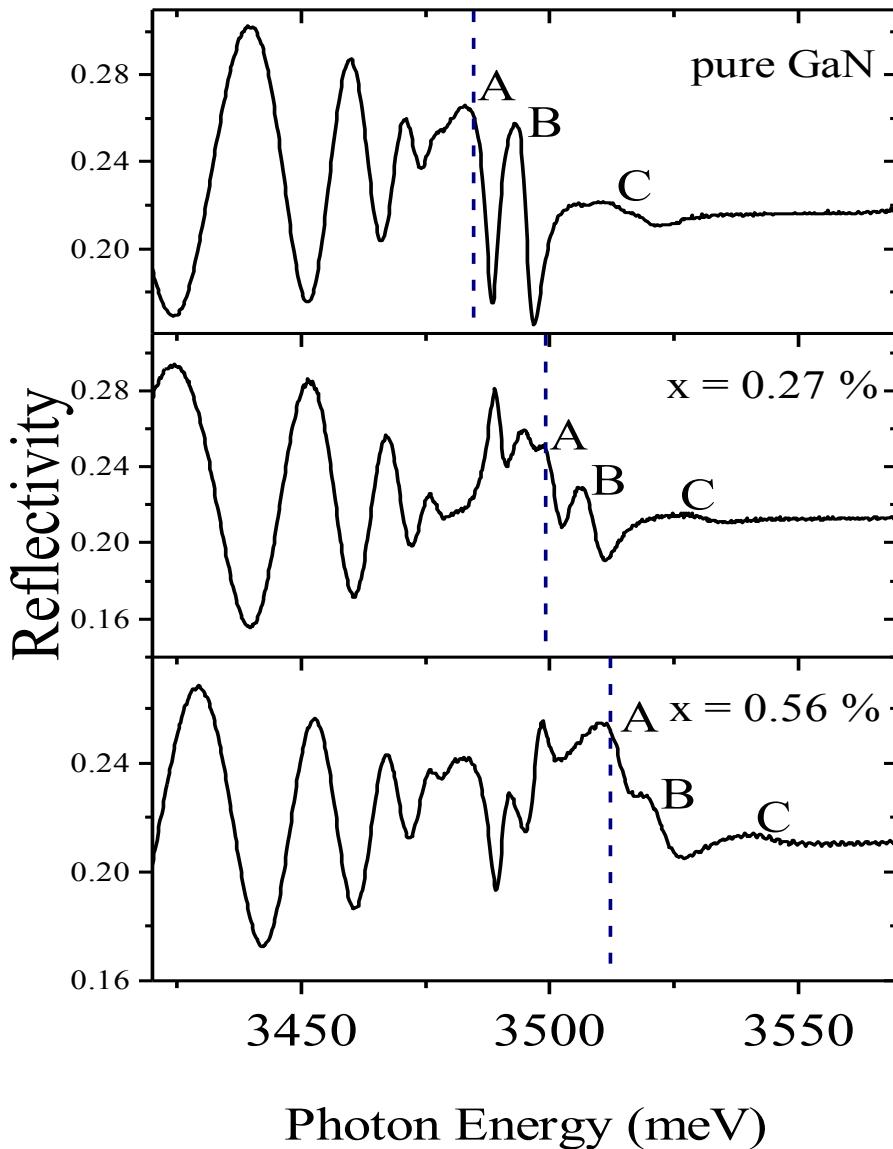


Excitons in GaN:Mn and GaN close spectrally but no strain in the structure

Experimental Setup



Results – zero field reflectivity

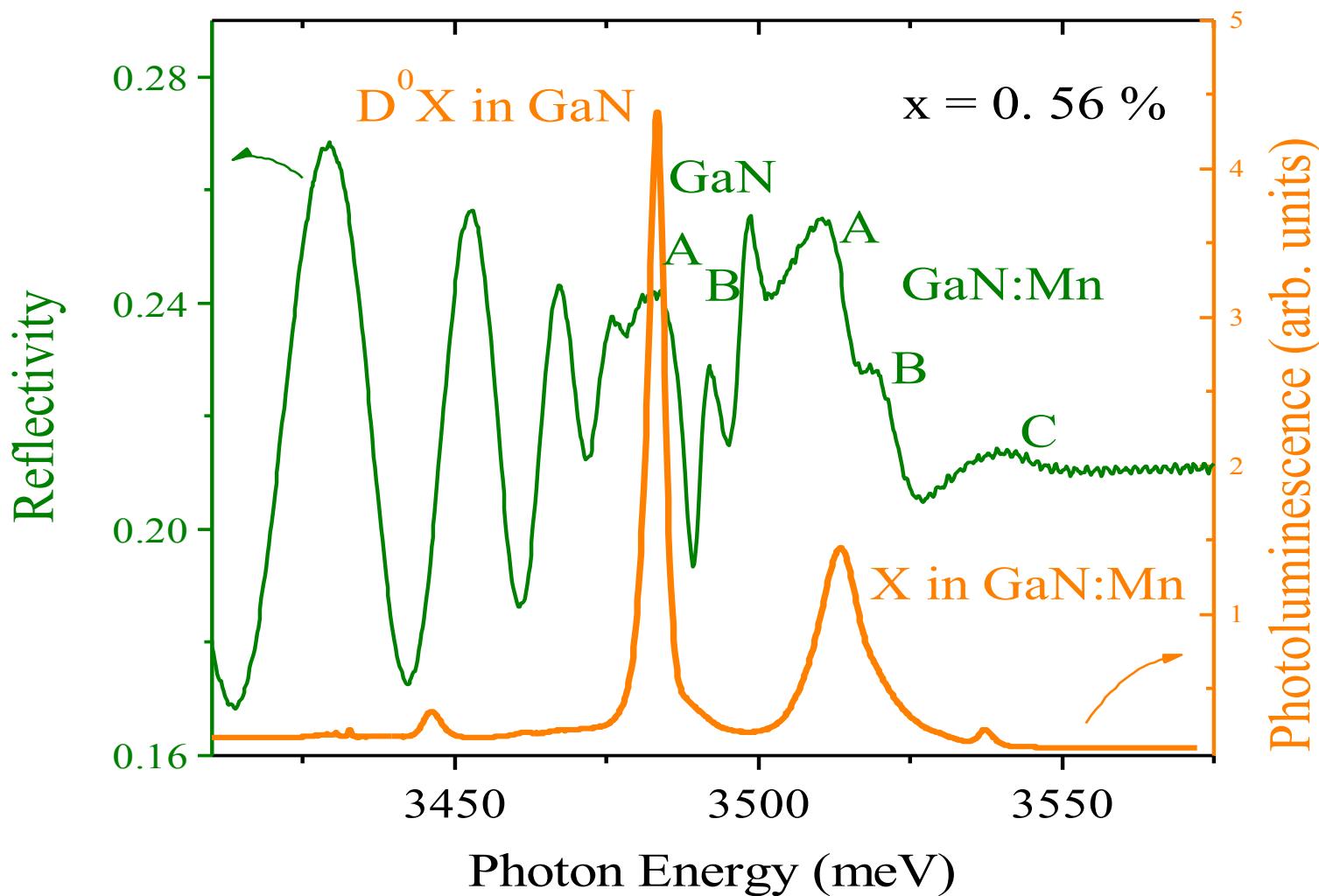


→ Contributions from GaN and GaN:Mn close spectrally and strong influence of interferences

→ Well resolved **A, B and C** excitons in GaN and GaN:Mn

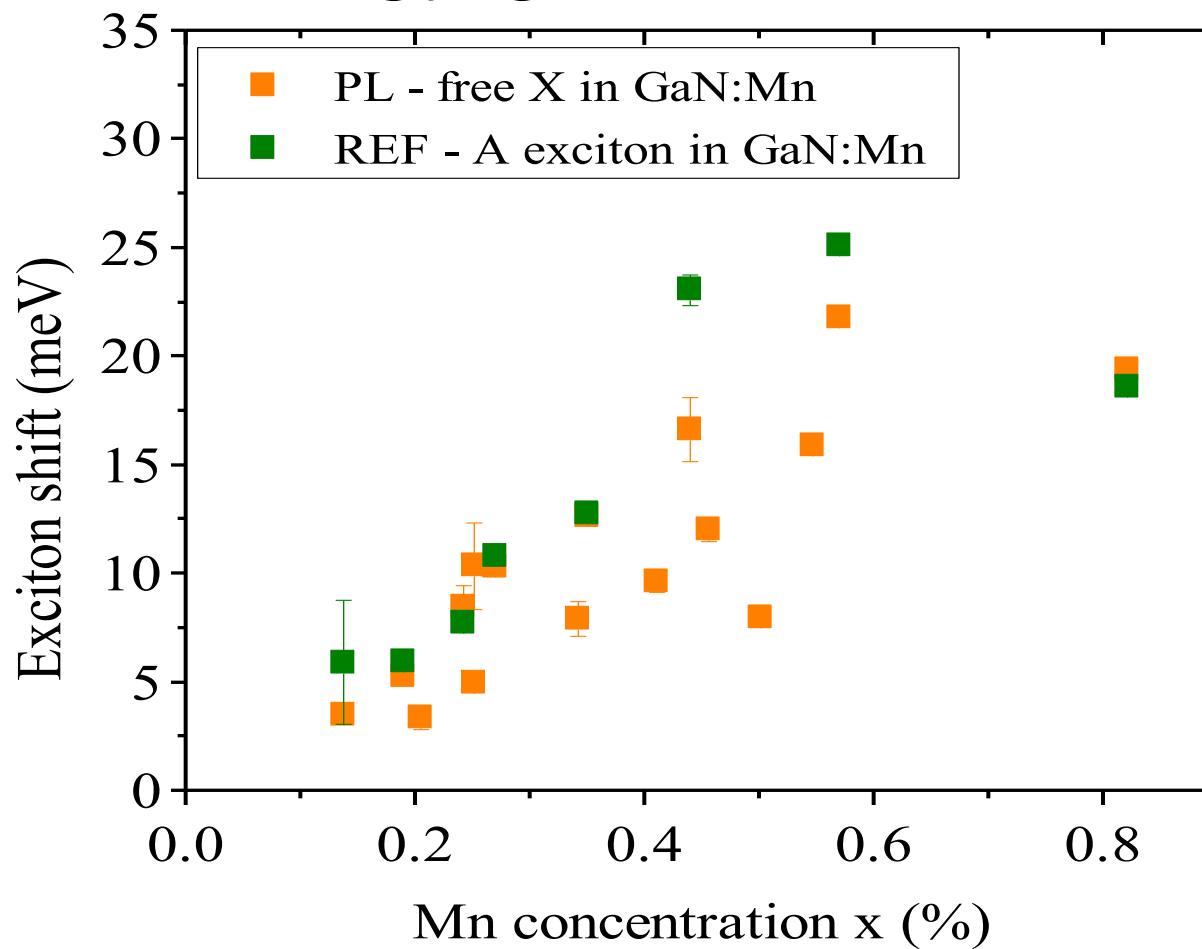
→ Excitons shift towards higher energy when Mn concentration increased

Results – zero field photoluminescence



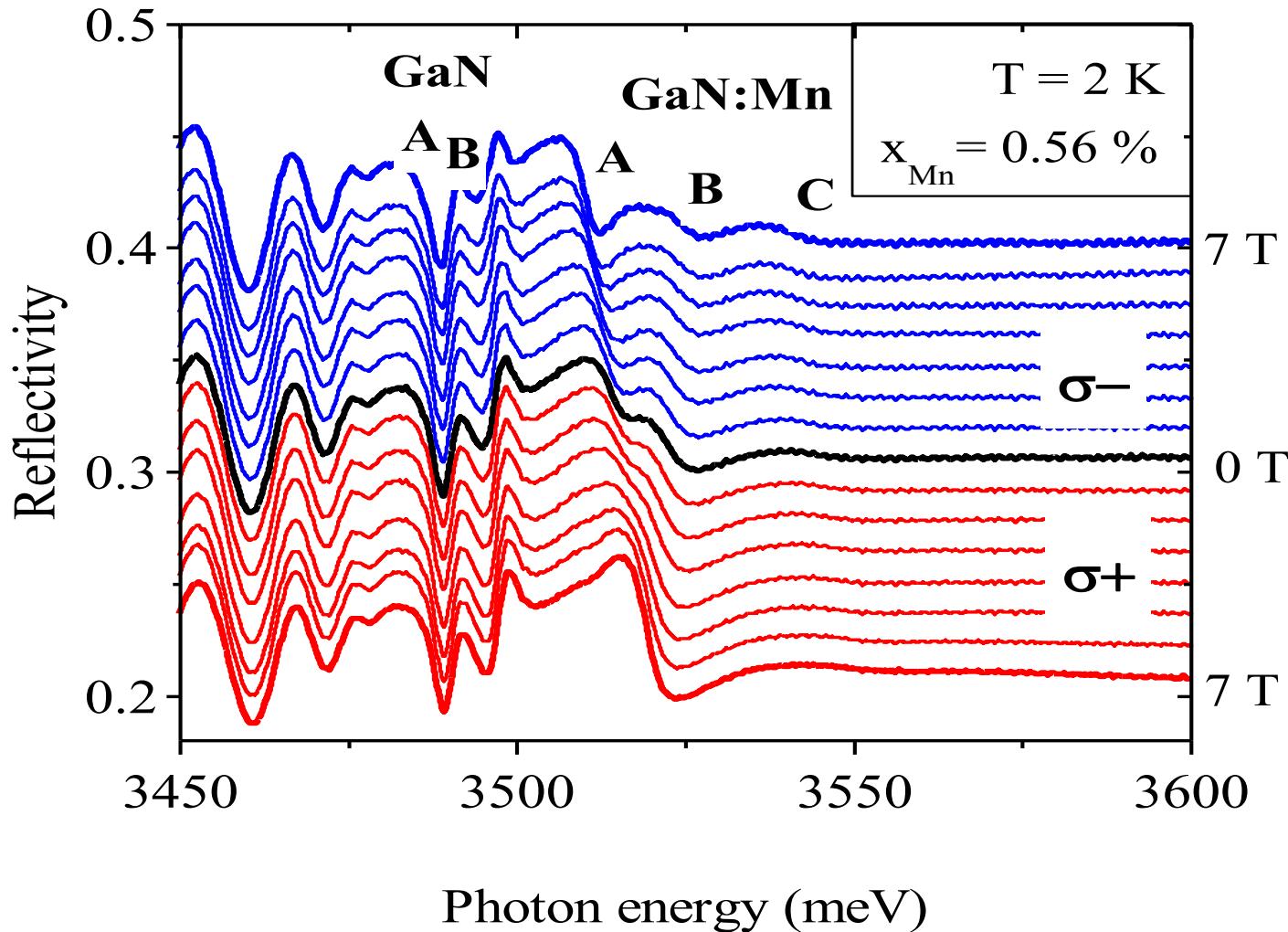
→ Exciton bound to neutral donor in GaN and free excitons in GaN:Mn transitions dominate PL spectra

GaN:Mn energy gap vs Mn concentration



- Increase of the GaN:Mn band gap with increasing Mn concentration
- Indication for the strong coupling between holes and Mn spins predicted by theory (Dietl, PRB 2008)

Results - magnetoreflectivity



→ Reflectivity in magnetic field confirms identification of excitonic transitions

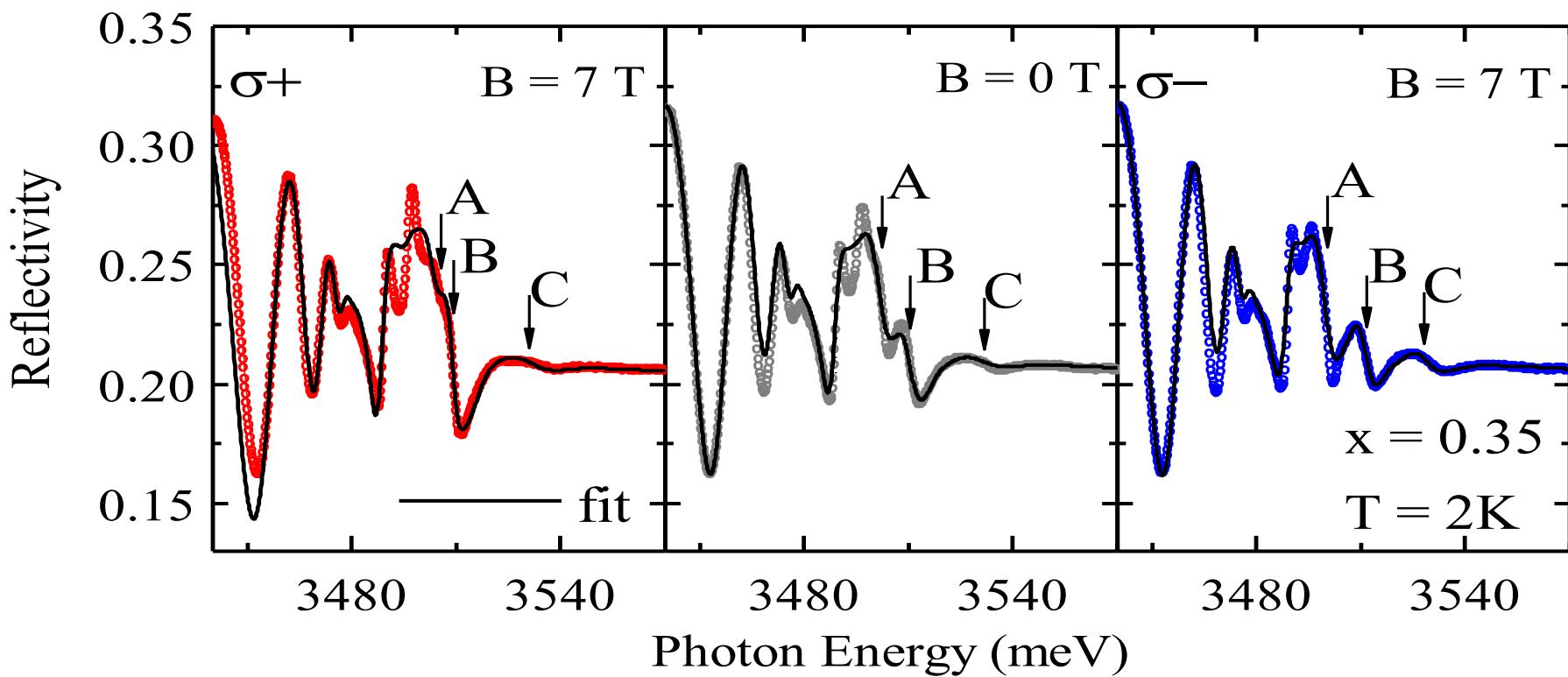
Modelling of the Reflectivity Spectra

Dielectric function for GaN and GaN:Mn layers:

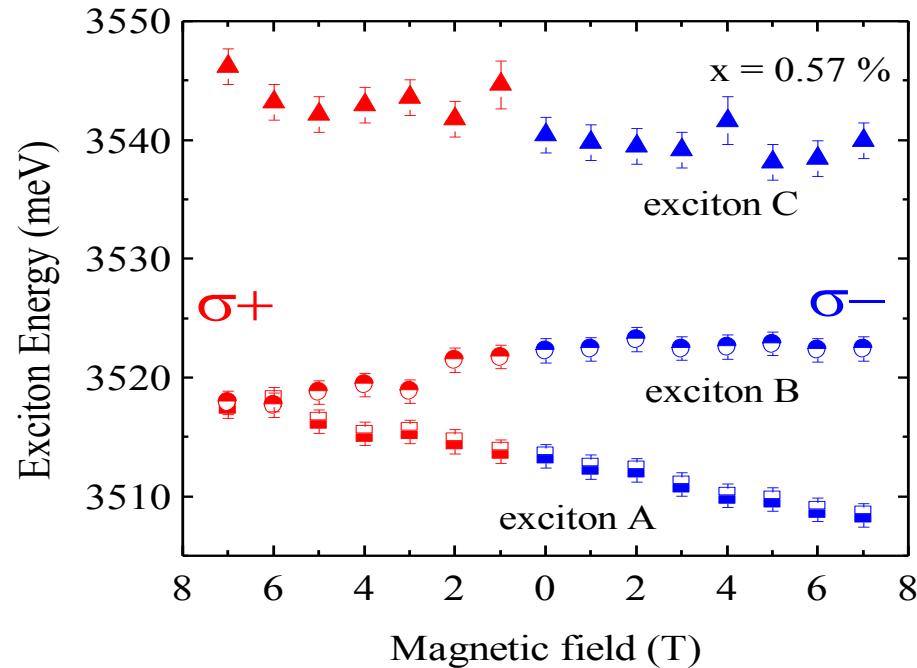
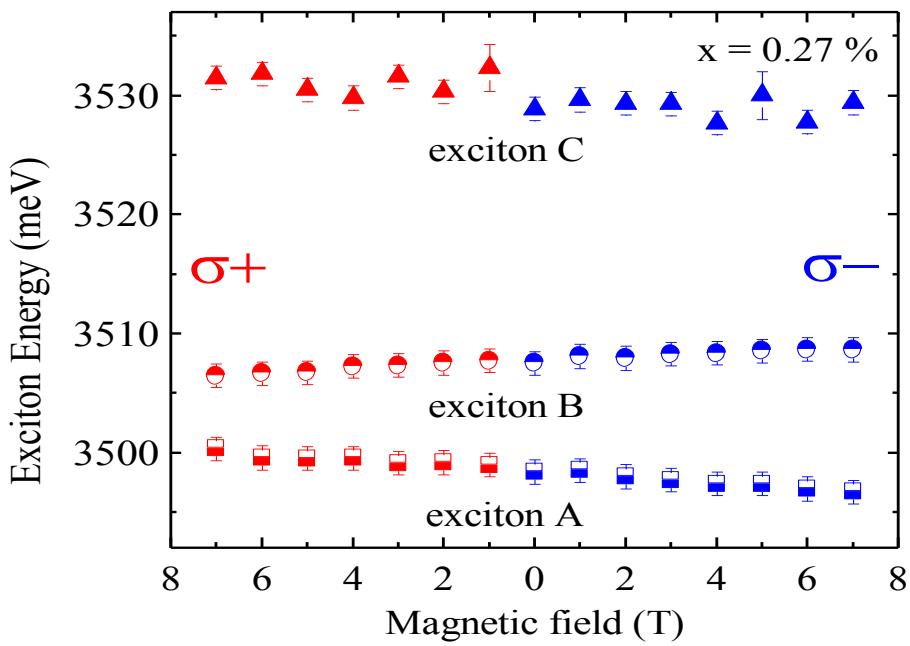
$$\varepsilon_j(E) = \varepsilon_0 + \frac{4\pi \cdot \alpha_{A_j} \cdot E_{A_j}^2}{(E_{A_j} - E)^2 - i \cdot E \cdot \Gamma_{A_j}} + \frac{4\pi \cdot \alpha_{B_j} \cdot E_{B_j}^2}{(E_{B_j} - E)^2 - i \cdot E \cdot \Gamma_{B_j}} + \frac{4\pi \cdot \alpha_{C_j} \cdot E_{C_j}^2}{(E_{C_j} - E)^2 - i \cdot E \cdot \Gamma_{C_j}} +$$

+ excitonic excited states + continuum of unbound states

Fitting parameters: energies, widths and polarizabilities of excitons A, B, C



Excitonic splitting in magnetic field



→ Observation of giant Zeeman splitting on A, B and C excitons in GaN:Mn

→ Due to anticrossings between excitons, excitonic splitting not proportional to magnetization

Modelling of the excitonic positions in magnetic field

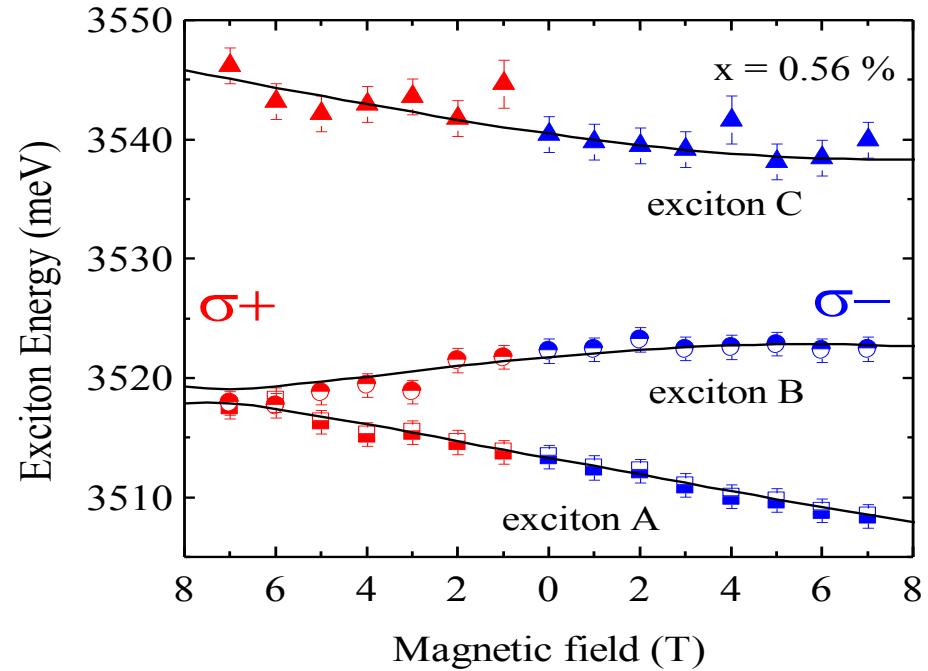
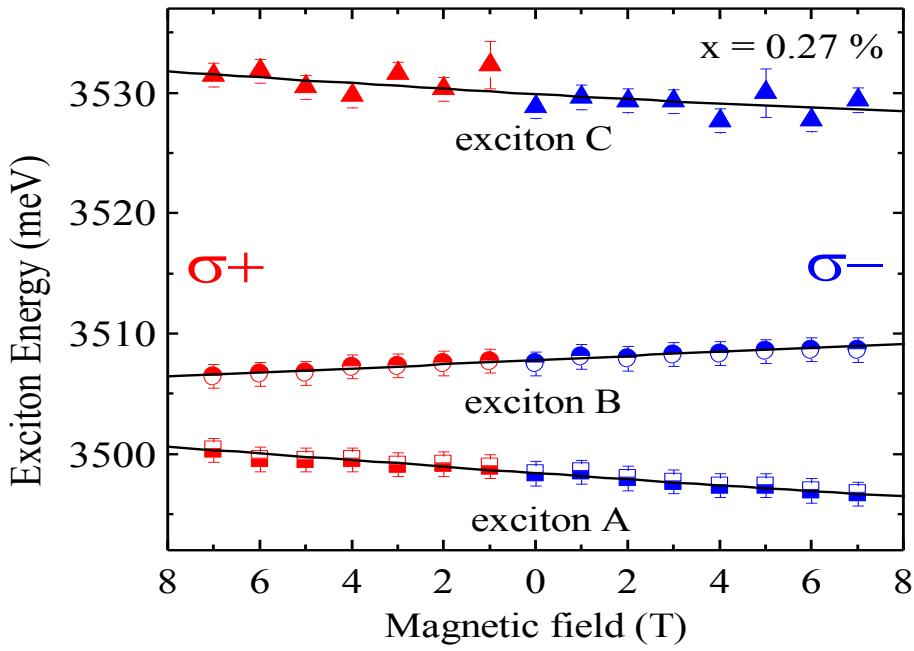
Effective Hamiltonian:

$$H = E_0 + H_V + H_{e-h} + H_{s,p-d} + H_{Zeeman} + H_{dia}$$

Hamiltonian of exchange interaction between Mn³⁺ ions and free carriers:

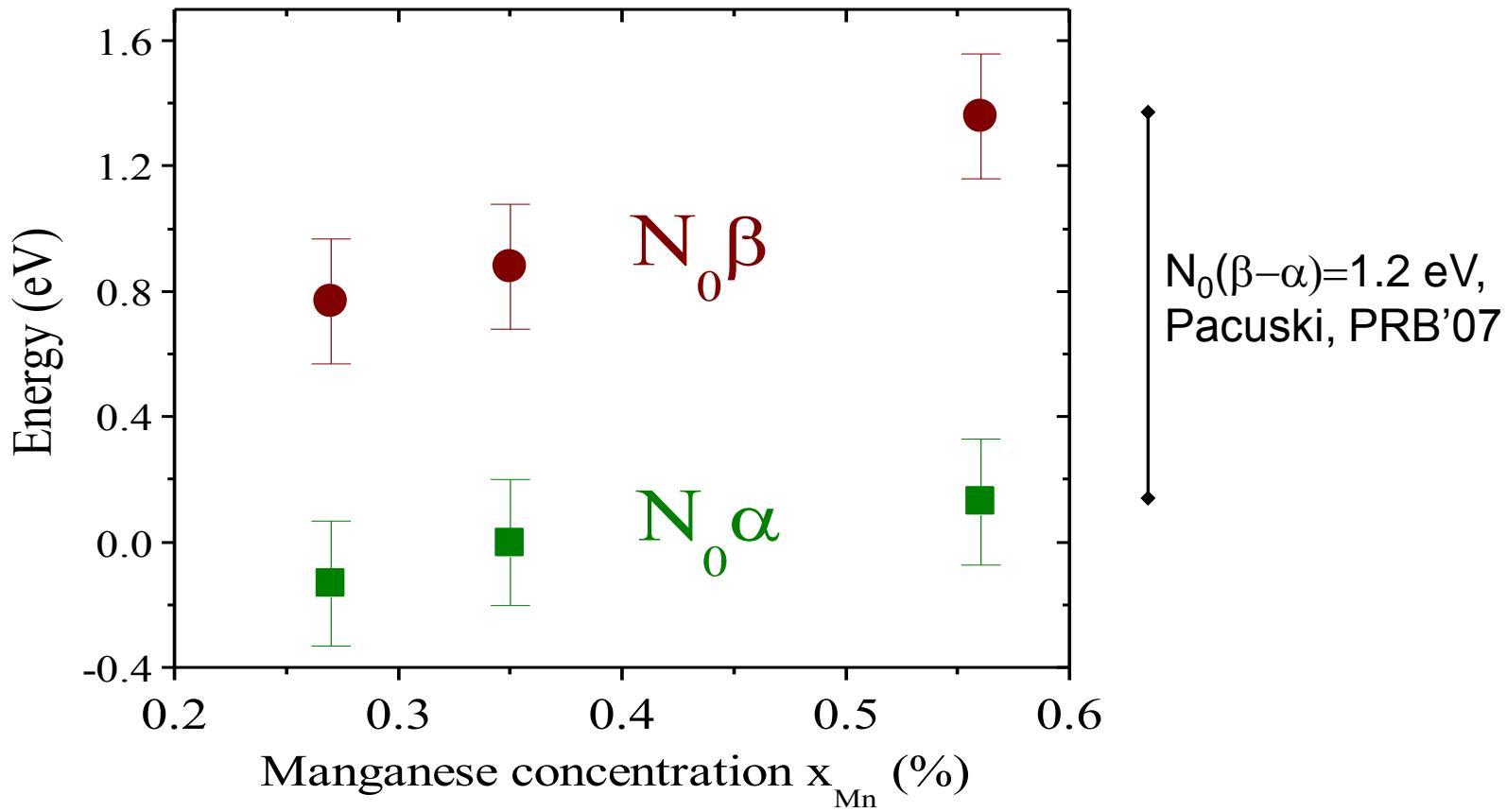
$$H_{s,p-d}^{\sigma\pm} = \pm \frac{1}{2} N_0 x_{Mn} \langle -S_z \rangle \begin{pmatrix} \beta - \alpha & 0 & 0 \\ 0 & \alpha - \beta & 0 \\ 0 & 0 & \alpha + \beta \end{pmatrix}$$

Excitonic splitting in magnetic field



- Free parameters of the fit: $N_0\alpha$, $N_0\beta$, band gap energy, Δ_1 , Δ_2
- Quantitative description of excitonic shifts in magnetic field

Apparent exchange constants



Apparent:

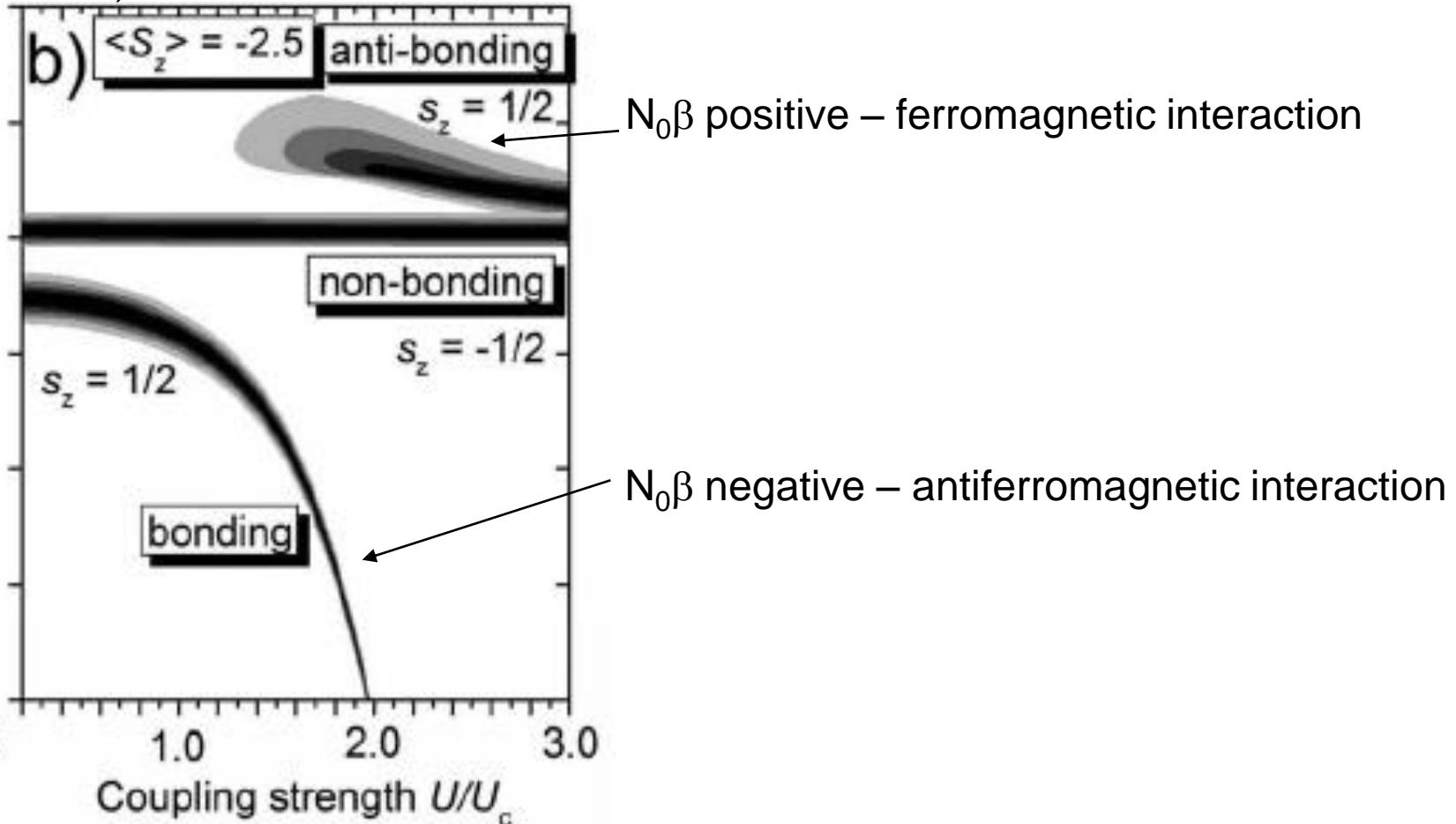
- $N_0 \beta$ positive \rightarrow delocalized hole-Mn³⁺ ion exchange interaction ferromagnetic
- $N_0 \alpha$ small \rightarrow small effective strength of exchange interaction electron-Mn³⁺ ion
- localizing potential of the Mn³⁺ ion (Dietl, PRB'08)

Summary

- Increase of the GaN:Mn band gap with increasing Mn content
- Mn^{3+} – band hole exchange interaction ferromagnetic
- Strong coupling between hole and Mn^{3+} ion
- Observation of giant Zeeman splitting of A, B **and C** excitons in GaN:Mn

Strong coupling regime

Dietl, PRB'08



Hv

Valence band at $k = 0$:

$$H_v = \begin{pmatrix} -\Delta_2 & 0 & 0 \\ 0 & \Delta_2 & -\sqrt{2}\Delta_3 \\ 0 & -\sqrt{2}\Delta_3 & \Delta_1 \end{pmatrix}$$

Δ_1 – trigonal component of crystal field and biaxial strain
 Δ_2, Δ_3 – anisotropic spin-orbit interactions